Logarithm ic roughening in a growth process with edge evaporation

Haye Hinrichsen

Theoretische Physik, Fachbereich 8, Universitat W uppertal, 42097 W uppertal, Germany

R oughening transitions are often characterized by unusual scaling properties. As an example we investigate the roughening transition in a solid-on-solid growth process with edge evaporation [Phys. Rev. Lett. 76, 2746 (1996)], where the interface is known to roughen logarithm ically with time. Performing high-precision simulations we not appropriate scaling forms for various quantities. M oreover we present a simple approximation explaining why the interface roughens logarithm ically.

I. IN TRODUCTION

A large variety of models for surface grow this known to display universal scaling laws [1, 2, 3, 4, 5]. In most cases one observes simple power-law scaling, i.e., the width W of an initially at interface grows with time as

where is the so-called growth exponent. In a nite system the width eventually saturates at a nite value W_{sat} , which grows with the linear system size L as

$$W_{sat}$$
 L; (2)

where is the roughness exponent. Both asymptotic power laws can be combined in a single scaling form

$$W (L;t) = L f(t=L^{2});$$
 (3)

where z = = is the dynam ic exponent and f is a scaling function with an appropriate asymptotic behavior. This type of power-law scaling, also known as Fam ily-V icsek scaling [6], is generic for a large num ber of self-sim ilar growth processes. However, in some cases the interface was found to roughen logarithm ically with time. This m ay happen, for example, when a system undergoes a roughening transition. The purpose of this paper is to study a simplem odelwith such a logarithm ic scaling behavior in more detail. To this end we consider a class of solid-on-solid growth models introduced a few years ago by A lon et al. [7, 8] which have the special feature that atom s can only evaporate at the edges of terraces. The models exhibit a robust phase transition from a nonmoving smooth phase to a moving phase, where the interface roughens continuously. Rem arkably, this roughening transition takes place even in one spatial dim ension. At the critical point the interface width was found to increase logarithm ically with time. However, so far it was in possible to unfold the complete scaling picture since previous num erical simulations were not accurate enough [8]. Here we close this gap by perform ing highprecision simulations based on a parallelized code. As a main result we nd that Eq. (3) has to be replaced by a logarithm ic scaling law of the form

$$W^{2}(L;t) = \ln L + f(t=L^{2});$$
 (4)

M oreover, we present a simple approximation which explains why the interface roughens logarithm ically.

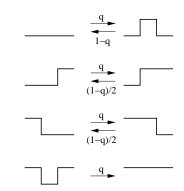


FIG.1: Dynamic rules for deposition (!) and evaporation () of the restricted m odel introduced in R ef. [7]. Note that evaporation from the middle of plateaus is not allowed.

II. GROW TH MODEL W ITH EVAPORATION AT THE EDGES OF PLATEAUS

The growth m odels investigated in Ref. [7] are de ned as solid-on-solid deposition-evaporation processes with the special property that atoms can only evaporate at the edges of terraces. The models are de ned on a ddimensional lattice with L sites and periodic boundary conditions, where each site i is associated with an integer variable h_i . In Ref. [7] two variants of models have been considered. Here we will focus on the physically motivated restricted model in one dimension, where the heights at neighboring sites obey the inequality

$$h_i = h_{i+1}j = 1$$
: (5)

The model evolves by random -sequential updates, i.e., a site i is random by selected and one of the following moves is carried out (see Fig. 1). With probability q an atom is deposited at site i, increasing h_i by 1.0 there ise one of the nearest neighbors is random by selected. If the selected neighbor is at a low erheight, indicating the edge of a terrace, an atom is removed from site i. In both cases a move is abandoned if the resulting con guration would violate the condition (5). Each attempted update corresponds to an average time increment t = 1=L.

In the limit L ! 1 the model has the following phenom enological properties. If the growth rate q is small, the interface is at and pinned to a spontaneously selected bottom layer. Small islands will occasionally grow

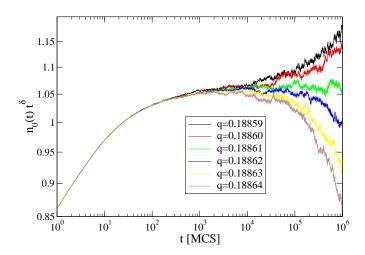


FIG.2: Density of exposed sites at the bottom layer n_0 (t) timest in a system with 32768 sites averaged over up to 1000 independent runs for di erent values of q.

on top of this bottom layer but will quickly be eliminated by desorption at the islands edges so that the system eventually reaches a stationary state characterized by a nite width. As q is increased, more and more islands on top of the bottom layer are produced, until above q_c , the critical value of q, the islands m erge and the interface starts m oving. Approaching q_c from below, the stationary width is found to diverge logarithm ically.

In R efs. [7,8] it was shown that the roughening transition in this class of models is driven by a directed percolation (DP) transition [9] at the spontaneously selected bottom layer. This means that the density of exposed sites at the bottom layer n_0 can be interpreted as the density of active sites in a DP process. Therefore, at criticality this density is expected to decay as

where $= = 2^{\circ}$ 0:1595 is one of the dynam ic critical exponents of DP in 1+1 dimensions. Similarly the criticalbehavior at the rst few layers above the bottom layer can be described in term s of unidirectionally coupled DP processes [10]. Roughly speaking each layer can be associated with a DP process which is coupled to the layer below. E ective couplings in opposite direction, which certainly exist in the model de ned above, turn out to be irrelevant. Field-theoretic renorm alization group studies revealed that the scaling exponents k and $\frac{1}{2}$ (and hence their ratio $z = k = \frac{1}{2}$) are the same at all levels, while the exponents associated with the order param eters decrease with increasing height above the bottom layer. Thus the concept of unidirectionally coupled DP successfully explains the critical behavior at the rst few layers above the bottom layer. However, it cannot predict the critical properties of the interface as a whole, especially the scaling of the interface width.

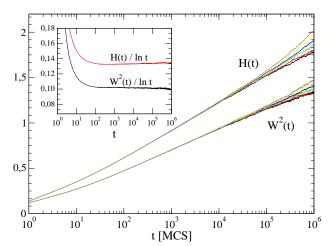


FIG.3: The squared interface width W 2 and the average height H as functions of tim e in a log-lin plot. The simulation parameters are the same as in Fig.2. The inset shows that both quantities increase logarithm ically at the critical point. Sm all deviations for t > 10^5 can be traced back to the onset of nite size e ects.

III. NUMERICAL SIMULATIONS

A. Scaling properties at the critical point

Performing high-precision simulations on a parallel computer we rst used Eq. (6) to estimate the critical threshold. As shown in Fig. 2 we obtain the result

$$q_c = 1:8861(1)$$
 (7)

which is much more accurate than the previous estimate reported in Ref. [7]. Moreover, our simulations con m that the dynamics at the bottom layer is indeed driven by a DP process.

At the critical point $q = q_c$ the average height

$$H = \frac{1}{L} \sum_{i=1}^{K^{L}} h_{i}$$
(8)

and the squared interface width

$$W^{2} = \frac{1}{L} \sum_{i=1}^{X^{L}} (h_{i} \quad H)^{2}$$
 (9)

are found to increase logarithm ically with time as

$$W^{2}(t)$$
 / $Int;$ (10)

where = 0.102 (3) and = 0.133 (3) (see Fig. 3). Thus, apart from di erent prefactors, the squared width and the mean height show the same type of logarithm ic behavior. We note that in a previous work the width was erroneously conjectured to increase as W (t) ($\ln t$)^{0.43} [8].

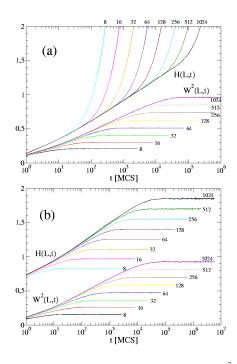


FIG.4: Finite size simulations: Squared width W² (L;t) and mean height H (L;t) averaged over at least 500 independent runs in a nite system with L = 8;16;32;:::;1024 sites for (a) periodic and (b) xed boundary conditions. In the lower panel the curves for H (t) have been shifted vertically.

B. Finite-size sim ulations

In a nite system the critical behavior depends on the type of the boundary condition. In what follows we consider (a) periodic and (b) D irichlet boundary conditions, where the sites at the boundary are xed at zero height. As shown in Fig. 4, the average height H (L;t) and the squared width W ² (L;t) rst increase logarithm ically until nite-size e ects become relevant and the system crosses over to a di erent regim e, where the width saturates. M easuring the saturation levels we nd that

$$W_{sat}^{2}(L)' A_{p;f} + _{p;f} \ln L;$$
 (12)

where the indices p; f stand for periodic and xed boundary conditions, respectively. Our best estimates are:

$$A_{p} = 0.16(1); \qquad p = 0.161(2)$$

$$A_{f} = 0.21(1); \qquad f = 0.163(2)$$
(13)

Apparently the amplitude is universal in the sense that it does not depend on the choice of the boundary condition.

Unlike the width, the interface height does only saturate if xed boundary conditions are used. Here we nd a sim ilar form ula

$$H_{sat}(L) ' B_{f} + f \ln L;$$
 (14)

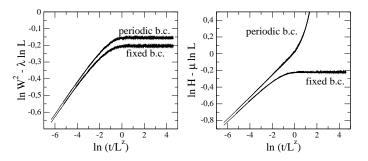


FIG.5: Finite size simulations: Data collapse of the curves shown in Fig. 4 according to the scaling forms (17) for L = $32;64;\ldots;1024$. In order to elim inate deviations due to initial transients all data points for t < 100 have been discarded.

where

$$B_f = 0.24(1); \quad f = 0.212(10): \quad (15)$$

In order to collapse the curves shown in Fig. 4, recall that the roughening transition in this model is driven by a 1+1-dimensional DP process at the bottom layer, which is characterized by a dynamic exponent

$$z = k = ? 1:5807:$$
 (16)

M oreover it has been shown that the critical dynam ics at the rst few layers is the same as in a sequence of unidirectionally coupled DP processes, which are all characterized by the same dynam ic exponent z. Therefore, it is reasonable to assume that the roughening transition as a whole is characterized by the dynam ic exponent of DP so that nite-size scaling functions can only depend on the scaling-invariant ratio t=L^z. Thus, the expected scaling form s read

$$W^{2}(L;t)' lnL + f(t=L^{z});$$

H(L;t)' lnL + q(t=L^{z}); (17)

where $f\left(\right. \right)$ and $g\left(\right. \right)$ are scaling functions w ith the asym p- totic behavior

$$f() = -\frac{1}{7}\ln ; \quad g() = -\frac{1}{7}\ln$$
 (18)

for ~!~ 0 and f () = A and g() = B for ~!~ 1 . In order to verify these scaling form s we plot W 2 (L;t)

 $\ln L$ and H (L;t) $\ln L$ versus t= L^{z} . As shown in Fig. 5, we obtain excellent data collapses.

C. O -critical simulations

A similar situation is encountered in o -critical simulations. In the subcritical regime $q < q_c$ the width and the average height saturate at

$$W_{sat}^{2}() = C \quad ln j j;$$

H_{sat}() = D $ln j j;$ (19)

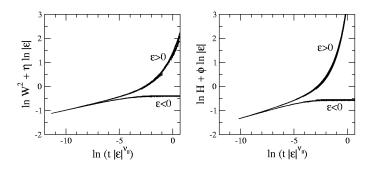


FIG. 6: O -critical simulations for = 0.0001, 0.0002, :::; 0.0128 on a chain with 32768 sites averaged over 200 independent runs. The gure shows data collapses according to the scaling forms (19). In order to elim inate deviations due to initial transients all data points for t < 100 have been rem oved.

where = q q denotes the distance from criticality. Following the same arguments as in the previous subsection, the conjectured scaling form s read

$$W^{2}(;t) = \ln j j + F(t j j);$$

H(;t) = ln j j + G(t j j); (20)

where $_{\rm k}$ ' 1:7338 is the tem poral scaling exponent of DP in 1+1 dimensions. These scaling forms are expected to hold not only below but also above criticality. In fact, plotting W²(;t)+ ln j jand H(;t)+ ln j jversus tj^{*}j (see Fig. 6), the best data collapses are obtained for

$$= 0:173(10); = 0:230(10); (21)$$

while the constants are estim ated by

$$C = 0:40(1);$$
 $D = 0:54(1):$ (22)

D . Relations am ong the am plitudes

O by iously the scaling form s (17) and (19) suggest that the exponentiated quantities $\exp(W^2)$ and $\exp(H)$ display ordinary power-law scaling. This would imply that the results for nite-size and o -critical scaling can be combined in a single scaling form, e.g.,

$$\exp \mathbb{W}^{2}(;L;t) = L \quad F'(L^{1=2};t=L^{2});$$

$$\exp \mathbb{H}(;L;t) = L \quad G'(L^{1=2};t=L^{2}):$$
(23)

This in turn would imply that the six amplitudes ;;;;;; introduced above, which now play the role of critical exponents, are no longer independent. Only two of them, say and , are independent while the others can be expressed as

$$\begin{array}{rcl}
= & = & _{2} & ; \\
= & = & _{2} & ; \\
= & = & _{k} & ; \\
= & = & _{k} & ; \\
\end{array}$$
(24)

quantity	am plitude	estim ate
W ² (t)		0:102(3)
H (t)		0:133(3)
W ² (L;t)	p	0:161(2)
W ² (L;t)	f	0:163(2)
H (L;t)	p	0:208 (10)
H (L;t)	f	0:212(10)
W ² (;t)		0:173(10)
H (;t)		0:230(10)

TABLE I: Sum m ary of the estim ated am plitudes.

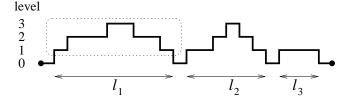


FIG.7: A pproximation of the average height by considering islands of size $i_1; i_2; i_3; \ldots$ (see text).

where $\frac{2}{2}$ ' 1:0968 and $\frac{1}{2}$ ' 1:7338. As shown in Table I these relations are compatible with the num erical results.

IV. SIMPLE APPROXIMATION

W hy does the interface roughen logarithm ically at the transition? To answer this question we present a simple approximation for the average interface height H (L) in a nite 1+1-dimensional system at criticality. We consider xed boundary conditions, i.e., the interface is pinned to the bottom layer at the two boundary sites. In between the interface may return to the bottom layer several times, dividing the chain into intervals of di erent lengths '1;'2;:::, as sketched in Fig.7. The approximation relies on the follow ing assumptions:

- 1. The probability distribution for the interval sizes ' is the same as the size distribution of inactive islands in a DP process, which is known to decrease as P (') $Y = \frac{2}{3} \frac{2}{3} \frac{1}{3} \frac$
- 2. A swe are using xed boundary conditions, we will assume that this probability distribution is cut o at the system size, i.e., P (`) = 0 for ` L.
- 3. The sites, where the interface touches the bottom layer, can be regarded as xed boundary conditions for the dynam ics taking place at the following layer.

W hile the rst two assumptions can be justi ed by numerical checks, the third assumption is crucial since the sites at the bottom layer evolve in time and can only be regarded as xed in an approximate sense. However, using this approximation we can derive a recursion relation since each island (for example the island encircled by the dotted line in Fig. 7) can be regarded as an independent growth process taking place in a nite system of size `with xed boundary conditions at the following layer. O byiously, the average height of such an island will be 1 + H (`). In order to calculate the average height of the entire interface H (L), one has to add up all these contributions weighted by the island size `. Replacing sum s by integrals, this leads to the integral equation

$$H (L) = \frac{{R_L \atop 0} d' 'P (') 1 + H (')}{{R_L \atop 0} d' 'P (')} :$$
(25)

Shifting the denom inator to the lhs. and di erentiating with respect to L we obtain

$$\frac{dH (L)}{dL} \int_{0}^{Z} d' P (') = LP (L); \qquad (26)$$

or equivalently

$$\frac{\mathrm{dH} (\mathrm{L})}{\mathrm{dL}} = \frac{\mathrm{d}}{\mathrm{dL}} \ln \int_{0}^{\mathrm{Z}_{\mathrm{L}}} \mathrm{d' 'P (');} \qquad (27)$$

leading to the solution

$$\begin{array}{c} Z_{L} \\ H(L) = \operatorname{const} + \ln \quad d``P(`) \\ 0 \\ = \operatorname{const} + - \ln L: \end{array}$$
(28)

Thus the approximation correctly reproduces the logarithm ic increase of the average height in a nite critical system. However, the predicted amplitude $= = \frac{1}{2}$ '0.25 di ers from the measured value 0.21.

A similar argument can be used to explain the logarithmic increase of the squared width. To this end we rst calculate the second moment of the height

$$M_{2}(L) = \frac{1}{L} \prod_{i=1}^{X^{L}} h_{i}^{2} :$$
 (29)

U sing the same assumptions as before, each island of size 'contributes to M $_2$ (L) with a term

$$M_{2}(')_{h! h+1} = 1 + 2H(') + M_{2}('):$$
 (30)

Replacing sum s by integrals we obtain the integral equation

$$M_{2}(L) = \frac{R_{L}}{0} d' P(') 1 + 2H(') + M_{2}(')}{R_{L}}; \quad (31)$$

leading to the di erential equation

$$\frac{dM_{2}(L)}{dL} \int_{0}^{Z_{L}} d' P (') = LP (L) + 2LP (L)H (L): (32)$$

In order to rem ove the mixed term on the r.h.s. we differentiate the squared width $W^{2}(L) = M_{2}(L) + H^{2}(L)$ with respect to L and combine the result with Eq. (26):

$$\frac{d \left[W^{2}(L) - M_{2}(L) \right]}{dL} \int_{0}^{L} d\mathbf{Y} (\mathbf{Y}) = 2LP(L)H(L);$$
(33)

Inserting Eq. (32) the m ixed term drops out and we obtain the di erential equation $\label{eq:eq:expansion}$

$$\frac{\mathrm{dW}^{2}(\mathrm{L})}{\mathrm{dL}} \int_{0}^{\mathrm{Z}_{\mathrm{L}}} \mathrm{d}' P (') = \mathrm{LP}(\mathrm{L}); \qquad (34)$$

which has exactly the same form as Eq. (26). Therefore, W 2 (L) and H (L) will only di er by a constant. Again the approximation correctly reproduces the logarithm ic increase but cannot predict the precise value of the am-plitude.

V. CONCLUSIONS

In the present paper we have analyzed the scaling behavior at the roughening transition of a restricted solidon-solid growth process with evaporation at the edges of terraces. Restricting to the case of a one-dimensional substrate we have carried out extensive M onte C arlo sim ulations, exceeding the temporal range of previous num erical studies by three decades. The num erical results con m that the transition is indeed driven by a directed percolation process at the bottom layer. Furtherm ore, they clearly show that squared interface width W 2 (t) and the average height above the bottom layer H (t) increase logarithm ically with time. Analyzing num erical data from nite-size and o -critical simulations we have postulated appropriate scaling form s which generate excellent data collapses. These scaling form s can be interpreted in such a way that the exponentiated quantities $\exp(M^2)$ and $\exp(H)$ obey ordinary power-law scaling, which allows one to derive various relations among the am plitudes. M oreover, we have presented a simple approximation which explains why W 2 and H grow logarithm ically.

In contrast to the expectations expressed in [8], we cannot nd evidence for several competing length scales. Moreover, there is no evidence for logarithmic scaling based on local scale invariance [11], rather the system shows ordinary scaling after an appropriate rede nition (exponentiation) of the order parameters.

Our results suggest that any roughening transition, which is driven by a phase transition from an active into an absorbing state at the bottom layer, should exhibit this type of logarithm ic roughening. An important example is a recently introduced model for dimer adsorption and desorption [12], where the transition is driven by a parity-conserving transition at the bottom layer. A cknow ledgem ents: The simulations were partly perform ed on the ALICE parallel computer at the IAI in W uppertal. I would like to thank B.O rth and G.A mold for technical support.

- [L] P. Meakin, The growth of fractal aggregates and their fractal measures, in Phase transitions and critical phenom ena, eds. C. D om b and J. L. Lebow itz, Vol. 12, A cadem ic Press, New York, 1988.
- [2] J. K rug and H. Spohn, K inetic roughening of growing surfaces, in Solids far from equilibrium, ed. by C. G odreche, C am bridge University P ress, U K., 1991.
- [3] A.J.McKane, M.Droz, J.Vannimenus, and D.E.Wolf, eds., Scale invariance, interfaces, and non-equilibrium dynamics, Plenum Press, New York, 1995.
- [4] A.L.Barabasiand H.Stanley, Fractal concepts in surface growth, C am bridge U niversity P ress, U K., 1995.
- [5] J.K rug, Adv. Phys. 46, 139 (1997).
- [6] F.Fam ily and T.Vicsek, J.Phys.A 18, L75 (1985).
- [7] U. Alon, M. Evans, H. Hinrichsen, and D. Mukamel, Phys. Rev. Lett. 76, 2746 (1996).
- [8] U.Alon, M.R.Evans, H.Hinrichsen, and D.Mukamel

Phys.Rev.E 57,4997 (1998).

- [9] For a recent review on directed percolation see e.g.: H. Hinrichsen, Adv. Phys. 49, 815 (2000).
- [10] U.C.Tauber, M.J.Howard, and H.Hinrichsen, Phys. Rev.Lett. 80, 2165 (1998); Y.Y.Goldschmidt, Phys. Rev.Lett. 81, 2178 (1998); Y.Y.Goldschmidt, H.Hinrichsen, M.J.Howard, and U.C.Tauber, Phys.Rev.E 59, 6381 (1999).
- [11] C. Tang, Scaling in avalanches and elsewhere, preprint NSF-ITP-89-118, unpublished; L.Sittler and H.H inrichsen, On generalized scaling laws with continuously varying exponents, eprint cond-m at/0208277.
- [12] H. Hinrichsen and G. Odor, Phys. Rev. Lett. 82, 1205 (1999); H. Hinrichsen and G. Odor, Phys. Rev. E 60, 3842 (1999).